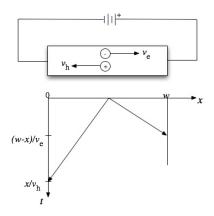
ECE228B Fiber Optic Components and Systems Homework #1

Problem 1:

Consider a semiconductor material exposed to an impulse of light at t=0 that generates N electron-hole pairs between 0 and w as shown below, with electron and hole velocities v_e and v_h .



Show that the hole and electron currents and total current can be written as follows:

$$i_{h}(t) = \begin{cases} -\frac{Nqv_{h}^{2}}{w^{2}}t + \frac{Nqv_{h}}{w}, \ 0 \le t \le \frac{w}{v_{h}}\\ 0, \text{ elsewhere} \end{cases}$$

$$i_{e}(t) = \begin{cases} -\frac{Nqv_{e}^{2}}{w^{2}}t + \frac{Nqv_{e}}{w}, \ 0 \le t \le \frac{w}{v_{e}}\\ 0, \text{ elsewhere} \end{cases}$$

$$i_{total}(t) = \begin{cases} \frac{Nq}{w} \Big[(v_{h} + v_{e}) - \frac{1}{w} (v_{h}^{2} + v_{e}^{2})t \Big], \ 0 \le t \le \frac{w}{v_{e}}\\ \frac{Nqv_{h}}{w} \Big[1 - \frac{v_{h}}{w}t \Big], \ \frac{w}{v_{e}} \le t \le \frac{w}{v_{h}} \end{cases}$$

Problem 2:

A p-i-n photodiode is able to convert a pulse of light with 8 x 10^{12} photons into 3 x 10^{12} electrons that contribute to the output photocurrent. Calculate the quantum efficiency η and the responsivity *R* at $\lambda_0 = 0.83 \mu m$, 1.3 μm and 1.55 μm . Now assume that the photodiode is composed of In_{0.70}Ga_{0.30}As_{0.64}P_{0.36} and that the intrinsic region perpendicular to the incident photons is 1 μm thick. Use the Figure in your class notes for absorption as a function of wavelength for different material systems/compositions to estimate the quantum efficiency and responsivity at $\lambda_0 = 1.3 \text{ mm}$.

Problem 3:

A silicon p-i-n photodiode operating with 0dBm input at 0.8 μ m has 20MHz bandwidth, 65% quantum efficiency, 1nA dark current and 8pf junction capacitance.

- (a) Determine the RMS current noise due to shot noise.
- (b) Determine the SNR due to shot noise.
- (c) If we require and SNR of 20dB, calculate the minimum received optical power when shot noise is the only noise source.

Problem 4:

An InGaAsP-InP FP laser has an optical cavity length of 350 μ m, and a gain medium with peak gain coefficient that can be approximated by the linear relation

$$g_p \approx \alpha \left(\frac{\Delta n}{\Delta n_T} - 1 \right)$$

Assume the injected carrier concentration for transparency $\Delta n_T \approx 1.75 \text{ X } 10^{18} \text{ cm}^{-3}$ and the semiconductor absorption in the absence of current injection $\alpha = 600 \text{ cm}^{-1}$, a FWHM gain bandwidth of approximately 5nm and a mode refractive index of $n'_{eff} = 4$.

- (A) Plot the peak gain coefficient as a function of the injected carrier concentration (Δn) from $\Delta n = 0$ to $\Delta n = 10 \Delta n_T$.
- (B) Calculate the separation between mode of the cavity, the number of modes that oscillate in the cavity and the mode integer M of the peak radiation.

Problem 5:

Consider a DFB laser with a 400 μ m long grating, an effective mode index 3.5 and a grating corrugation period 0.22 μ m. Calculate the symmetric modes (wavelengths) that the laser will operate at assuming no $\lambda/4$ phase shift in the grating. What will be the output wavelength if the grating is fabricated with a $\lambda/4$ phase shift in the grating?

Problem 6:

Calculate and plot the wavelength shift vs. tuning current for a tunable Bragg reflector that operates based on the free-carrier plasma effect. Assume $\lambda_g = 1300$ nm InGaAsP tuning region operated at 1500 nm, $\beta_{pl} = -1.3 \times 10^{-20}$ cm³, active region with L = 400µm, d = 0.3µm, w = 2 µm and confinement factor $\Gamma_t = 0.3$. For the material assume an infinite spontaneous recombination time constant, bimolecular recombination constant B = 10^{-10} cm³/s and Auger recombination constant C = 3×10^{-29} cm⁶/s.

Problem 7:

For a mode-locked laser, assume the envelopes are given by the expression below and that the phases are equal. v_m is the frequency spacing of mode *m*, where m=0 coincides with the central frequency of the atomic lineshape. Determine expressions for the mean power, peak power and pulse width (defined at the full-width half-maximum FWHM).

$$A_q = \sqrt{P} \frac{\left(\Delta \nu/2\right)^2}{\left(m\nu_m\right)^2 + \left(\Delta \nu/2\right)^2}, \ m = -\infty, \dots, +\infty$$